

Content

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Editorial	224
Semiconductor Physics	
Calculation of spin-Hamiltonian constants for extended defects (vSi-vC)0 (ky5) in silicon carbide polytype 3C-SiC	
<i>B. Shanina, V. Bratus'</i>	225-230
Condensons and bicondensons in one-dimensional system	
<i>N.I. Kashirina, O.A. Korol</i>	231-237
Inversion of spin levels in exchange-coupled pairs under combined time reversal	
<i>I.I. Geru</i>	238-248
Electron and hole effective masses in heavily boron doped silicon nanostructures determined using cyclotron resonance experiments	
<i>D.V. Savchenko, E.N. Kalabukhova, B.D. Shanina, N.T. Bagraev, L.E. Klyachkin, A.M. Malyarenko, V.S. Khromov</i>	249-255
Current and electroluminescence intensity oscillations under bipolar lateral electric transport in the double-GaAs/InGaAs/GaAs quantum wells	
<i>M.M. Vinogradskii, P.A. Belevskii, V.M. Poroshin, O.S. Pilipchuk, V.O. Kochelap</i>	256-262
Semiconductor surface spectroscopy using transverse acousto-electric effect: role of surface charge in photo-processes at ZnS/Si interface	
<i>N.P. Tatyanchenko, N.N. Roshchina, V.L. Gromashevskii, G.S. Svechnikov, L.V. Zavyalova, B.A. Snopok</i>	263-272
Studying the mechanical properties of (Cu_{1-x}Ag_x)₇GeS₅I mixed crystals by using the micro-indentation method	
<i>V.V. Bilanych, A.V. Bendak, K.V. Skubenchuk, A.I. Pogodin, V.S. Bilanych, I.P. Studenyak</i>	273-276
Features of electrochemical processes at the boundary p-GaAs – HF water solution	
<i>G.A. Pashchenko, M.Yu. Kravetskyi, L.I. Trishchuk</i>	277-281
Hetero- and low-dimensional structures	
Growth of silicon self-assembled nanowires by using gold-enhanced CVD technology	
<i>A.I. Klimovskaya, Yu.Yu. Kalashnyk, A.T. Voroshchenko, O.S. Oberemok, Yu.M. Pedchenko, P.M. Lytvyn</i>	282-287
Optics	
Electronic structure and optical properties of HgSe	
<i>J.O. Akinlami, O.O. Odeyemi</i>	288-293
Optoelectronics and optoelectronic devices	
Be-ion implanted p-n-InSb diode for infrared applications. Modeling, fabrication and characterization	
<i>V. Koroteyev, V. Kochelap, S. Sapon, B. Romaniuk, V. Melnik, O. Dubikovskyi, T. Sabov</i>	294-306
Sensors	
The role of shear modulus and viscosity of thin organic films on the adsorption response of QCM sensors	
<i>Z.I. Kazantseva, I.A. Koshelets, Yu.M. Shirshov, V.I. Kalchenko</i>	307-314
Lectures, Presentations	
<i>(For subscribers only)</i>	
To 100-year anniversary of Prof. M.F. Deigen	
<i>B. Shanina</i>	315
Inversion of spin levels in exchange-coupled pairs under combined time reversal	
<i>I. Geru</i>	315
Condensons and bicondensons in low-dimensional systems	
<i>N. Kashirina</i>	316
M.F. Deigen and electron-phonon interaction	
<i>V.O. Kochelap</i>	316
Information	
For contributors to SPQEO	
	317-318